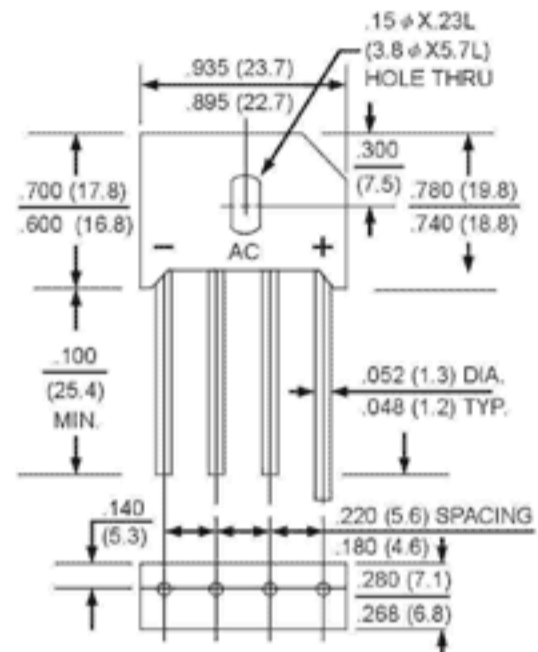


## SILICON BRIDGE RECTIFIERS

REVERSE VOLTAGE - 50 to 1000 Volts  
FORWARD CURRENT - 4 / 6 / 8 Amperes

### FEATURES

- Surge overload rating - 150~200 amperes peak
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique
- Plastic material has Underwriters Laboratory Flammability classification 94V-0
- Mounting Position: Any
- Mounting Torque: 5 In. lb. Max.



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	KBU4A	KBU4B	KBU4D	KBU4G	KBU4J	KBU4K	KBU4M	UNIT
	KBU6A	KBU6B	KBU6D	KBU6G	KBU6J	KBU6K	KBU6M	
	KBU8A	KBU8B	KBU8D	KBU8G	KBU8J	KBU8K	KBU8M	
	RS601	RS602	RS603	RS604	RS605	RS606	RS607	
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Bridge Input Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Output Current at T <sub>C</sub> =100°C T <sub>A</sub> =50°C/40°C/45°C	KBU4	4.0	KBU6 RS6	6.0	KBU8	8.0	A	
Peak Forward Surge Current, 8.3ms single half sine-wave super imposed on rated load (JEDEC Method)		4.0		6.0		6.0	200	A
Maximum Instantaneous Forward Voltage Drop per Element at 3.0A/3.0/4.0A		150		170		200	A	
Maximum Reverse Leakage at rated DC Blocking Voltage per Element T <sub>A</sub> = 25°C T <sub>C</sub> =100°C		1.0		1.0		1.0	V	
Operating and Storage Temperature Range T <sub>J</sub> , T <sub>STG</sub>	10	100	10	200	10	300	μA mA	
	-40 to +125							°C